

KSD1047

Audio Power Amplifier DC to DC Converter

- High Current Capability
- High Power Dissipation
- Complement to KSB817



NPN Planar Silicon Transistor

Absolute Maximum Ratings $T_C=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage	160	V
V _{CEO}	Collector-Emitter Voltage	140	V
V _{EBO}	Emitter-Base Voltage	6	V
I _C	Collector Current (DC)	8	Α
I _{CP}	*Collector Current (Pulse)	16	Α
P _C	Collector Dissipation (T _C =25°C)	80	W
TJ	Junction Temperature	150	°C
T _{STG}	Storage Temperature	- 40 ~ 150	°C

Electrical Characteristics $T_C=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	$I_C = 5mA, I_E = 0$	160			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C = 10mA, R _{BE} =∞	140			V
BV _{EBO}	Emitter-Base Breakdown Voltage	$I_E = 5mA, I_C = 0$	6			V
I _{CBO}	Collector Cut-off Current	$V_{CB} = 80V, I_{E} = 0$			0.1	mA
I _{EBO}	Emitter Cut-off Current	$V_{EB} = 4V, I_{C} = 0$			0.1	mA
h _{FE1}	* DC Current Gain	$V_{CE} = 5V, I_{C} = 1A$	60		200	
h _{FE2}	DC Current Gain	$V_{CE} = 5V, I_{C} = 6A$	20			
V _{CE} (sat)	Collector-Emitter Saturation Voltage	$I_C = 5A, I_B = 0.5A$			2.5	V
V _{BE} (on)	Base-Emitter ON Voltage	$V_{CE} = 5V, I_{C} = 1A$			1.5	V
f _T	Current Gain Bandwidth Product	$V_{CE} = 5V, I_{C} = 1A$		15		MHz
C _{ob}	Output Capacitance	V _{CB} = 10V, f = 1MHz		210		pF
t _{ON}	Turn ON Time	V _{CC} = 20V		0.26		μs
t _F	Fall Time	$I_C = 1A = 10I_{B1} = -10I_{B2}$		0.68		μs
t _{STG}	Storage Time	$R_L = 20\Omega$		6.88		μs
* Pulse test: PW=2		•	•	•	•	

* h_{FE} Classificntion

Classification	0	Y	
h _{FE1}	60 ~ 120	100 ~ 200	

Typical Characteristics

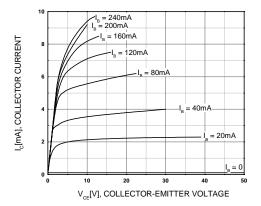


Figure 1. Static Characteristic

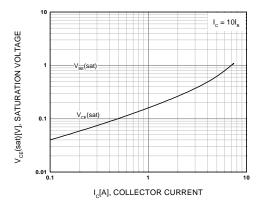


Figure 3. Collector-Emitter Saturation Voltage

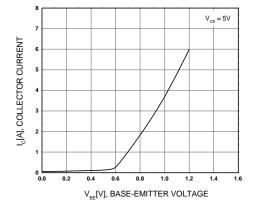


Figure 5. Base-Emitter On Voltage

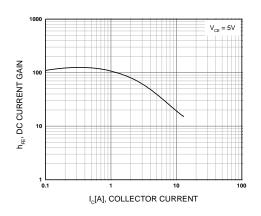


Figure 2. DC current Gain

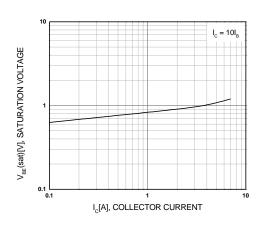


Figure 4. Base-Emitter Saturation Voltage

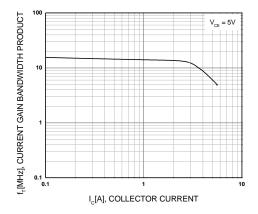


Figure 6. Current Gain Bandwidth Product

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Typical Characteristics (Continued)

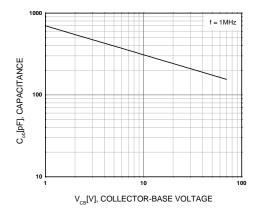


Figure 7. Collector Output Capacitance

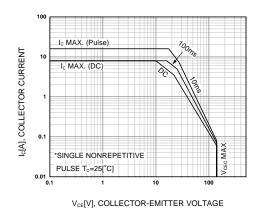


Figure 8. Safe Operating Area

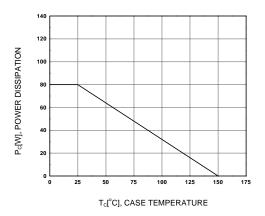
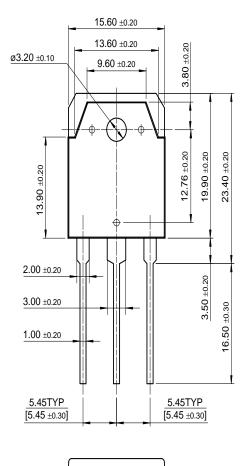


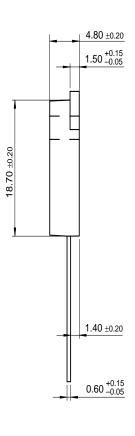
Figure 9. Collector Output Capacitance

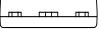
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Package Demensions

TO-3P







Dimensions in Millimeters

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